



# Dual, 12-Bit, Parallel Input, Multiplying Digital-to-Analog Converter

#### **FEATURES**

- ±1LSB INL
- 2.5V to 5.5V Supply Operation
- Fast Parallel Interface:17ns Write Cycle
- Update Rate of 20.4MSPS
- 10MHz Multiplying Bandwidth
- ±15V Reference Input
- Extended Temperature Range: -40°C to +125°C
- 40-Lead QFN
- 12-Bit Monotonic
- 4-Quadrant Multiplication
- Power-On Reset with Brownout Detection
- Readback Function
- Industry-Standard Pin Configuration
- Pin-Compatible with the AD5405

#### **APPLICATIONS**

- Portable Battery-Powered Instruments
- Waveform Generators
- Analog Processing
- Programmable Amplifiers and Attenuators
- Digitally-Controlled Calibration
- Programmable Filters and Oscillators
- Ultrasound

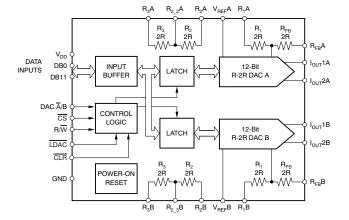
#### **DESCRIPTION**

The DAC7822 is a dual, CMOS, 12-bit, current output digital-to-analog converter (DAC). This device operates from a 2.5V to 5.5V power supply, making it suitable for battery-powered and many other applications.

The DAC7822 operates with a fast parallel interface. Data readback allows the user to read the contents of the DAC register via the DB pins. On power-up, the internal register and latches are filled with zeroes and the DAC outputs are at zero scale.

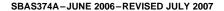
The DAC7822 offers excellent 4-quadrant multiplication characteristics, with large signal multiplying bandwidth of 10MHz. The applied external reference input voltage ( $V_{REF}$ ) determines the full-scale output current. An integrated feedback resistor ( $R_{FB}$ ) provides temperature tracking and full-scale voltage output when combined with an external current-to-voltage precision amplifier. The DAC7822 also includes the resistors necessary for 4-quadrant multiplication and other configuration modes.

The DAC7822 is available in a 40-lead QFN package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.







This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **PACKAGE/ORDERING INFORMATION**

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

### **ABSOLUTE MAXIMUM RATINGS**(1)

Over operating free-air temperature range (unless otherwise noted).

	DAC7822	UNIT
V <sub>DD</sub> to GND	-0.3 to +7.0	V
Digital input voltage to GND	-0.3 to V <sub>DD</sub> + 0.3	V
V <sub>OUT</sub> to GND	-0.3 to V <sub>DD</sub> + 0.3	V
Operating temperature range	-40 to +125	°C
Storage temperature range	-65 to +150	°C
Junction temperature (T <sub>J</sub> max)	+150	°C
ESD Rating, HBM	2000	V
ESD Rating, CDM	1000	V

<sup>(1)</sup> Stresses above those listed under absolute maximum ratings may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.



### **ELECTRICAL CHARACTERISTICS**

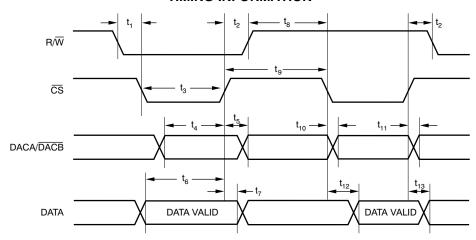
 $V_{DD}$  = +2.5V to +5.5V;  $I_{OUT}1$  = Virtual GND;  $I_{OUT}2$  = 0V;  $V_{REF}$  = 10V;  $T_A$  = full operating temperature. All specifications -40°C to +125°C, unless otherwise noted.

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNITS
STATIC PERFORMANCE					'	
Resolution			12			Bits
Relative accuracy					±1	LSB
Differential nonlinearity					±1	LSB
Output leakage current		Data = 000h, T <sub>A</sub> = +25°C			±1	nA
Output leakage current		Data = 000h, T <sub>A</sub> = T <sub>MAX</sub>			±15	nA
Full-scale gain error		All ones loaded to DAC register		±10	±25	mV
Full-scale tempco <sup>(1)</sup>				±5		ppm/°C
Bipolar zero-code error		Circuit configuration as shown in Figure 41			±25	mV
Output capacitance		DAC latches leaded with all 1s		25	30	pF
REFERENCE INPUT					'	
V <sub>REF</sub> range			-15		15	V
V <sub>REF</sub> A, V <sub>REF</sub> B, Input resistance			8	10	12	kΩ
R <sub>1</sub> , R <sub>FB</sub> resistance			17	20	25	kΩ
R <sub>2</sub> , R <sub>3</sub> resistance			17	20	25	kΩ
V <sub>REF</sub> A to V <sub>REF</sub> B Input Mismatch				1.6	2.5	%
R <sub>2</sub> to R <sub>3</sub> Mismatch				0.06	0.18	%
LOGIC INPUTS AND OUTPUT <sup>(1)</sup>						
	١,,	V <sub>DD</sub> = +2.5V			0.6	V
Input low voltage	$V_{IL}$	$V_{DD} = +2.5V$ $V_{DD} = +5V$			0.8	V
lanut binb valtana	١,,	$V_{DD} = +2.5V$	2.1			V
Input high voltage	$V_{IH}$	V <sub>DD</sub> = +5V	2.4			V
Input leakage current	I <sub>IL</sub>				1	μA
Input capacitance	$C_IL$				10	pF
POWER REQUIREMENTS						
$V_{DD}$			2.5		5.5	V
I <sub>DD</sub> (normal operation)		Logic inputs = 0V			5	μA
$V_{DD} = +4.5V \text{ to } +5.5V$		V <sub>IH</sub> = V <sub>DD</sub> and V <sub>IL</sub> = GND		8.0	5	μA
$V_{DD} = +2.5V \text{ to } +3.6V$		$V_{IH} = V_{DD}$ and $V_{IL} = GND$		0.4	2.5	μΑ
AC CHARACTERISTICS <sup>(1)</sup>			•		,	
Output voltage settling time					0.2	μs
Reference multiplying BW		V <sub>REF</sub> = 7V <sub>PP</sub> , Data = FFFh		10		MHz
DAC glitch impulse		V <sub>REF</sub> = 0V to 10V, Data = 7FFh to 800h to 7FFh		10		nV-s
Feedthrough error V <sub>OUT</sub> /V <sub>REF</sub>		Data = 000h, V <sub>REF</sub> = 100kHz		-70		dB
Digital feedthrough				2		nV-s
Total harmonic distortion				-105		dB
Output spot noise voltage				25		nV/√ <del>Hz</del>

<sup>(1)</sup> Specified by design and characterization; not production tested.



#### **TIMING INFORMATION**



### **TIMING REQUIREMENTS: 2.5V to 5.5V**

At  $t_r$  =  $t_f$  = 1ns (10% to 90% of  $V_{DD}$ ) and timed from a voltage level of ( $V_{IL}$  +  $V_{IH}$ )/2;  $V_{DD}$  = 2.5V to 5.5V,  $V_{REF}$  = 10V,  $I_{OUT}$ 2 = 0V. All specifications –40°C to +125°C, unless otherwise noted.

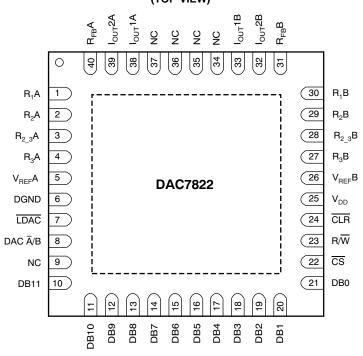
		D	AC7822			
PARAMETER (1)	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
t <sub>1</sub>	R/W to CS setup time	0	<del></del>		ns	
t <sub>2</sub>	R/W to CS hold time	0	<del></del>		ns	
t <sub>3</sub>	CS low time (write cycle)	10	·		ns	
t <sub>4</sub>	Address setup time	10	<del></del>		ns	
t <sub>5</sub>	Address hold time	0	<del></del>		ns	
t <sub>6</sub>	Data setup time	6	·		ns	
t <sub>7</sub>	Data hold time	0	·		ns	
t <sub>8</sub>	R/W high to CS low	5	·		ns	
t <sub>9</sub>	CS minimum high time	7	<del></del>		ns	
t <sub>10</sub>	Address setup time (Read Cycle)	0	<del></del>		ns	
t <sub>11</sub>	Address hold time (Read Cycle)	0	<del></del>		ns	
t <sub>12</sub>	Data access time		5	35	ns	
t <sub>13</sub>	Bus relinquish time		5	10	ns	

<sup>(1)</sup> Ensured by design; not production tested.



#### **DEVICE INFORMATION**

#### RTA PACKAGE QFN-40 (TOP VIEW)



#### **TERMINAL FUNCTIONS**

PIN NO.	PIN NAME	DESCRIPTION
1-4	R <sub>1</sub> A, R <sub>2</sub> A, R <sub>2_3</sub> A, R <sub>3</sub> A	DAC A 4-Quadrant Resistors. Allows a number of configuration modes, including bipolar operation with minimum of external components.
5, 26	V <sub>REF</sub> A, V <sub>REF</sub> B	DAC Reference Voltage Input Terminals.
6	DGND	Digital Ground Pin.
7	LDAC	Load DAC Input. Allows asynchronous or synchronous updates to the DAC output. The DAC is asynchronously updated when this signal goes low. Alternatively, if this line is held permanently low, an automatic or synchronous update mode is selected whereby the DAC is updated on the rising edge of CS.
8	DAC A/B	Selects DAC A or B. Low selects DAC A, and high selects DAC B.
9, 34-37	NC	Not internally connected.
10-21	DB11 to DB0	Parallel Data Bits 11 through 0.
22	<del>cs</del>	Chip Select Input; active low. Used in conjuction with $R/\overline{W}$ to load parallel data to the input latch or to read data from the DAC register. Edge sensitive; when pulled high, the DAC data is latched.
23	R/₩	Read/Write. When low, used in conjunction with $\overline{\text{CS}}$ to load parallel data. When high, used in conjunction with $\overline{\text{CS}}$ to read back contents of DAC register.
24	CLR	Active Low Control Input. Clears DAC output and input and DAC registers.
25	V <sub>DD</sub>	Positive Power Supply Input. These parts can be operated from a supply of 2.5V to 5.5V.
27-30	R <sub>3</sub> B, R <sub>2_3</sub> B, R <sub>2</sub> B, R <sub>1</sub> B	DAC B 4-Quadrant Resistors. Allow a number of configuration modes, including bipolar operation with a minimum of external components.
31, 40	R <sub>FB</sub> B, R <sub>FB</sub> A	External Amplifier Output.
32	I <sub>OUT</sub> 2B	DAC A Analog Ground. This pin typically should be tied to the analog ground of the system, but can be biased to achieve single-supply operation.
33	I <sub>OUT</sub> 1B	DAC B Current Output.
38	I <sub>OUT</sub> 1A	DAC A Current Output.
39	I <sub>OUT</sub> 2A	DAC A Analog Ground. This pin typically should be tied to the analog ground of the system, but can be biased to achieve single-supply operation.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = +5V

At  $T_A = +25^{\circ}C$ ,  $+V_{DD} = +5V$ , unless otherwise noted.

#### Channel A

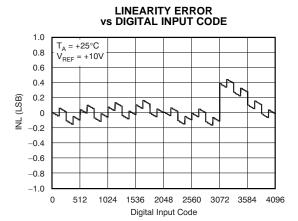


Figure 1.

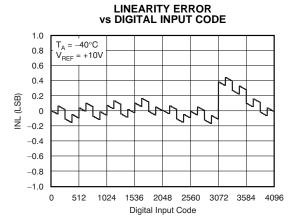


Figure 3.

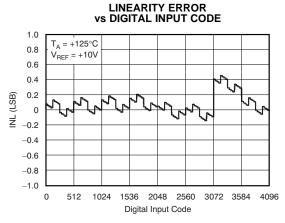


Figure 5.

# DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE

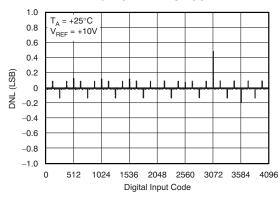


Figure 2.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

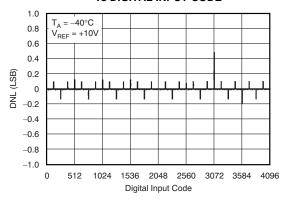


Figure 4.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

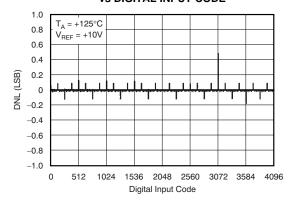


Figure 6.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = +5V (continued)

At  $T_A = +25$ °C,  $+V_{DD} = +5V$ , unless otherwise noted.

#### Channel B

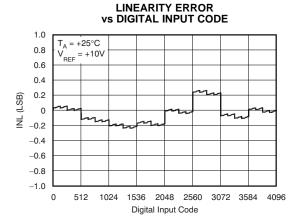


Figure 7.

LINEARITY ERROR

#### **vs DIGITAL INPUT CODE** 1.0 T<sub>A</sub> = -40°C 0.8 $V_{REF} = +10V$ 0.6 0.4 0.2 -0.4-0.6-0.8 -1.0 0 512 1024 1536 2048 2560 3072 3584 4096

Digital Input Code Figure 9.

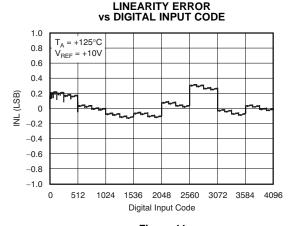


Figure 11.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

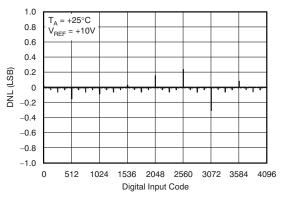


Figure 8.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

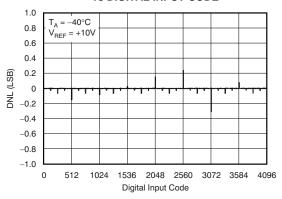


Figure 10.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

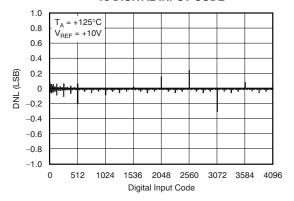


Figure 12.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = +5V (continued)

At  $T_A = +25$ °C,  $+V_{DD} = +5V$ , unless otherwise noted.

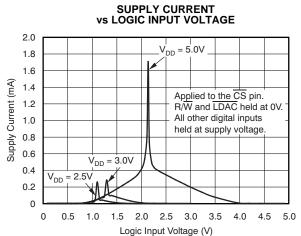


Figure 13.

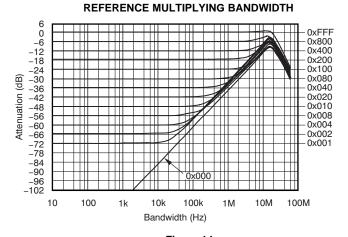


Figure 14.

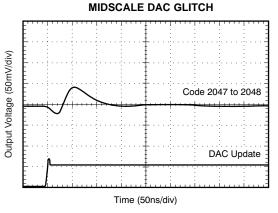


Figure 15.

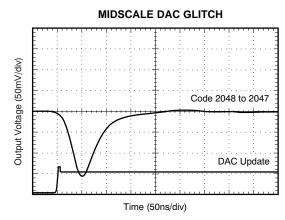


Figure 16.

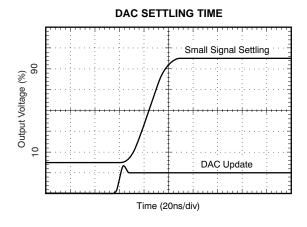


Figure 17.

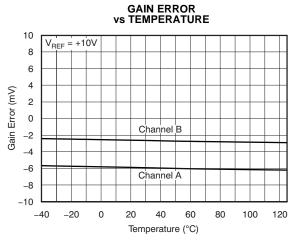


Figure 18.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = +5V (continued)

At  $T_A = +25$ °C,  $+V_{DD} = +5V$ , unless otherwise noted.

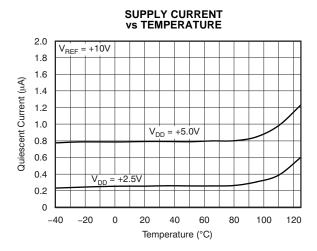


Figure 19.

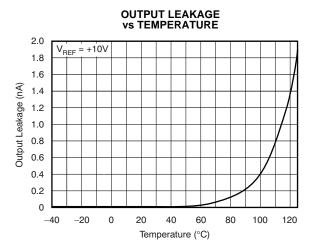


Figure 20.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = +2.5V

At  $T_A = +25^{\circ}C$ ,  $+V_{DD} = +2.5V$ , unless otherwise noted.

#### Channel A

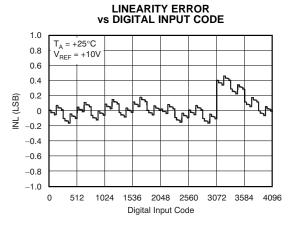


Figure 21.

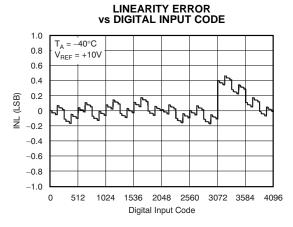


Figure 23.

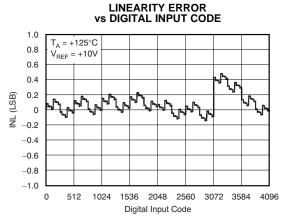


Figure 25.

# DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE

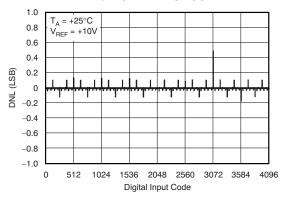


Figure 22.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

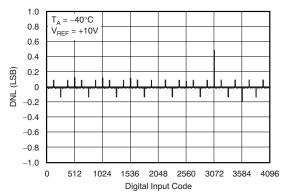


Figure 24.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

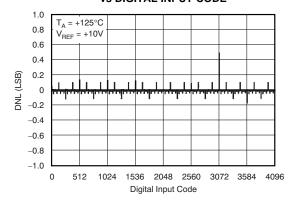


Figure 26.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = +2.5V (continued)

At  $T_A = +25$ °C,  $+V_{DD} = +2.5$ V, unless otherwise noted.

#### Channel B

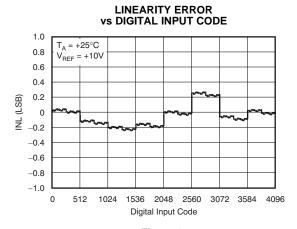


Figure 27.

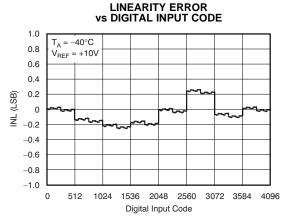


Figure 29.

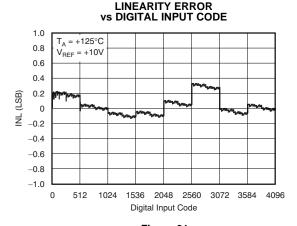


Figure 31.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

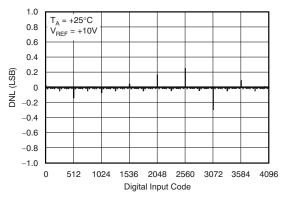


Figure 28.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

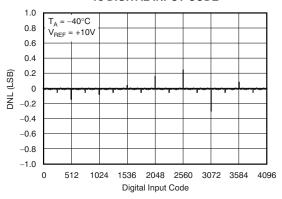


Figure 30.

# DIFFERENTIAL LINEARITY ERROR vs DIGITAL INPUT CODE

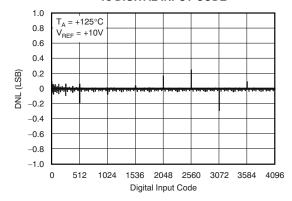


Figure 32.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = +2.5V (continued)

At  $T_A = +25$ °C,  $+V_{DD} = +2.5$ V, unless otherwise noted.

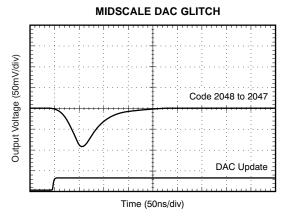


Figure 33.

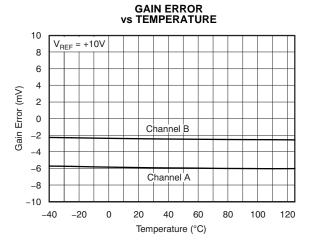


Figure 35.

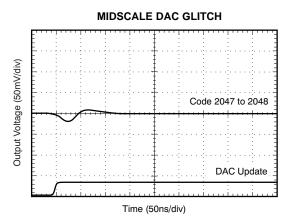


Figure 34.

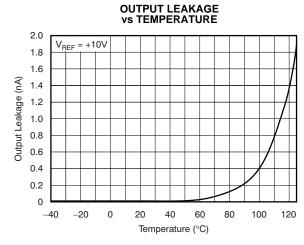


Figure 36.



#### THEORY OF OPERATION

The DAC7822 is a dual channel, current output, 12-bit, digital-to-analog converter (DAC). The architecture, illustrated in Figure 37, is an R-2R ladder configuration with the three MSBs segmented. Each 2R leg of the ladder is either switched to  $I_{OUT}1$  or the  $I_{OUT}2$  terminal. The  $I_{OUT}1$  terminal of the DAC is held at a virtual GND potential by the use of an external I/V converter op amp. The R-2R ladder is connected to an external reference input  $V_{REF}$  that determines the DAC full-scale current. The R-2R ladder presents a code-independent load impedance to the external reference of  $10k\Omega \pm 20\%$ . The external reference voltage can vary over a range of -15V to +15V, thus providing bipolar  $I_{OUT}$  current operation. By using an external I/V converter and the DAC7822  $R_{FB}$  resistor, output voltage ranges of  $-V_{REF}$  to  $V_{REF}$  can be generated.

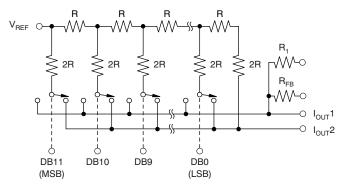


Figure 37. Equivalent R-2R DAC Circuit

When using an external I/V converter and the DAC7822  $R_{FB}$  and  $R_1$  resistors, the DAC output voltage is given by Equation 1:

$$V_{OUT} = -V_{REF} \times \frac{CODE}{4096}$$
 (1)

Each DAC code determines the 2R leg switch position to either GND or  $I_{OUT}$ . Because the DAC output impedance as seen looking into the  $I_{OUT}1$  terminal changes versus code, the external I/V converter noise gain also changes. Because of this, the external I/V converter op amp must have a sufficiently low offset voltage such that the amplifier offset is not modulated by the DAC  $I_{OUT}1$  terminal impedance change. External op amps with large offset voltages can produce INL errors in the transfer function of the DAC7822 as a result of offset modulation versus DAC code.

For best linearity performance of the DAC7822, a low input offset voltage op amp (such as the OPA277) is recommended (see Figure 38). This circuit allows  $V_{RFF}$  swinging from -10V to +10V.

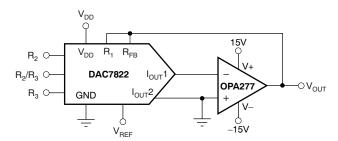


Figure 38. Voltage Output Configuration



#### **APPLICATION INFORMATION**

### **Stability Circuit**

For a current-to-voltage design (see Figure 39), the DAC7822 current output ( $I_{OUT}$ ) and the connection with the inverting node of the op amp should be as short as possible and according to correct printed circuit board (PCB) layout design practices. For each code change, there is a step function. If the gain bandwidth product (GBP) of the op amp is limited and parasitic capacitance is excessive at the inverting node, then gain peaking is possible. Therefore, for circuit stability, a compensation capacitor  $C_1$  (1pF to 5pF typ) can be added to the design, as shown in Figure 39.

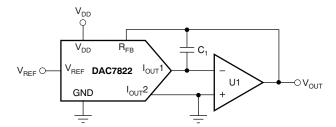


Figure 39. Gain Peaking Prevention Circuit with Compensation Capacitor

#### **Amplifier Selection**

There are many choices and many differences in selecting the proper operational amplifier for a multiplying DAC (MDAC). Making the analog signal out of the MDAC is one critical aspect. However, there are also other issues to take into account such as amplifier noise, input bias current, and offset voltage, as well as MDAC resolution and glitch energy. Table 1 and Table 2 suggest some suitable operational amplifiers for low power, fast settling, and high-speed applications. A greater selection of operational amplifiers can be found at www.ti.com/amplifer.

**Table 1. Suitable Precision Operational Amplifiers from Texas Instruments** 

PRODUCT	TOTAL SUPPLY VOLTAGE (V) (min)	TOTAL SUPPLY VOLTAGE (V) (max)	I <sub>Q</sub> PER CHANNEL (max) (mA)	GBW (typ) (MHz)	SLEW RATE (typ) (V/µs)	OFFSET DRIFT (typ) (μV/°C)	I <sub>IB</sub> (max) (pA)	CMRR (min) (dB)	PACKAGE/ LEAD	DESCRIPTION
Low Power										
OPA703	4	12	0.2	1	0.6	4	10	70	SOT5-23, PDIP-8, SOIC-8	12V, CMOS, Rail-to-Rail I/O, Operational Amplifier
OPA735	2.7	12	0.75	1.6	1.5	0.01	200	115	SOT5-23, SOIC-8	0.05µV/°C (max), Single-Supply CMOS Zero-Drift Series Operational Amplifier
OPA344	2.7	5.5	0.25	1	1	2.5	10	80	SOT5-23, PDIP-8, SOIC-8	Low Power, Single-Supply, Rail-To-Rail Operational Amplifiers MicroAmplifier Series
OPA348	2.1	5.5	0.065	1	0.5	2	10	70	SC5-70, SOT5-23, SOIC-8	1MHz, 45µA, Rail-to-Rail I/O, Single Op Amp
OPA277	4	36	0.825	1	0.8	0.1	1000	130	PDIP-8, SOIC-8, SON-8	High Precision Operational Amplifiers
Fast Settling			J.							
OPA350	2.7	5.5	7.5	38	22	4	10	76	MSOP-8, PDIP-8, SOIC-8	High-Speed, Single-Supply, Rail-to-Rail Operational Amplifiers MicroAmplifier Series
OPA727	4	12	6.5	20	30	0.6	500	86	MSOP-8, SON-8	e-trim 20MHz, High Precision CMOS Operational Amplifier
OPA227	5	36	3.8	8	2.3	0.1	10000	120	PDIP-8, SOIC-8	High Precision, Low Noise Operational Amplifiers



PRODUCT	SUPPLY VOLTAGE (V)	GBW PRODUCT (MHz)	VOLTAGE NOISE nV/√Hz	GBW (typ) (MHz)	SLEW RATE (V/µs)	V <sub>os</sub> (typ) (μV)	V <sub>OS</sub> (max) (μV)	CMRR (min) (dB)	PACKAGE/ LEAD	DESCRIPTION
Single Chann	el									
THS4281	±2.7 to ±15	38	12.5	35	500	3500	500	1000	SOT5-23, MSOP-8, SOIC-8	Very Low-Power High Speed Rail-To-Rail Input/Output Voltage Feedback Operational Amplifier
THS4031	±4.5 to ±16.5	200	1.6	100	500	3000	3000	8000	CDIP-8, MSOP-8, SOIC-8	100-MHz Low Noise Voltage-Feedback Amplifier
THS4631	±4.5 to ±16.5	210	7	900	260	2000	50pA	2	SOIC-8, MSOP-8	High Speed FET-Input Operational Amplifier
OPA656	±4 to ±6	230	7	290	250	2600	2pA	5pA	SOIC-8, SOT5-23	Wideband, Unity Gain Stable FET-Input Operational Amplifier
OPA820	±2.5 to ±6	280	2.5	240	200	1200	900	23,000	SOIC-8, SOT5-23	Unity Gain Stable, Low Noise, Voltage Feedback Operational Amplifier
<b>Dual Channe</b>										
THS4032	±4.5 to ±16.5	200	1.6	100	500	3000	3000	8000	SOIC-8, MSOP-8	100-MHz Low Noise Voltage-Feedback Amplifier, Dual
OPA2822	±2 to ±6.3	220	2	170	200	1200	9600	12000	SOIC-8, MSOP-8	SpeedPlus Dual Wideband, Low-Noise Operational Amplifier

#### **Positive Voltage Output Circuit**

As Figure 40 illustrates, in order to generate a positive voltage output, a negative reference is input to the DAC7822. This design is suggested instead of using an inverting amp to invert the output as a result of resistor tolerance errors. For a negative reference,  $V_{OUT}$  and GND of the reference are level-shifted to a virtual ground and a -2.5V input to the DAC7822 with an op amp.

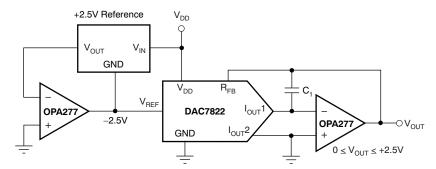


Figure 40. Positive Voltage Output Circuit

#### **Bipolar Output Section**

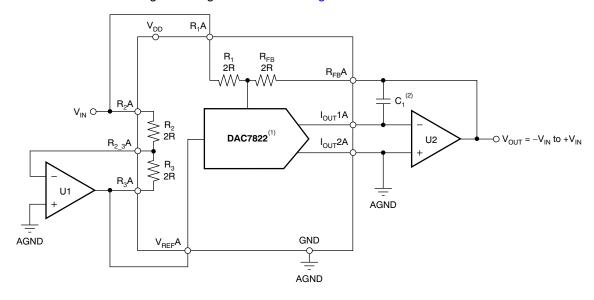
The DAC7822, as a 2-quadrant multiplying DAC, can be used to generate a unipolar output. The polarity of the full-scale output  $I_{OUT}$  is the inverse of the input reference voltage at  $V_{RFF}$ .

Some applications require full 4-quadrant multiplying capabilities or bipolar output swing. As shown in Figure 41, external op amp U2 is added as a summing amp and has a gain of 2X that widens the output span to 5V. A 4-quadrant multiplying circuit is implemented by using a 2.5V offset of the reference voltage to bias U2. According to the circuit transfer equation given in Equation 2, input data (D) from code 0 to full-scale produce output voltages of  $V_{OUT} = -2.5V$  to  $V_{OUT} = +2.5V$ .

$$V_{OUT} = \left(\frac{D}{0.5 \times 2^{N}} - 1\right) \times V_{REF}$$
 (2)



External resistance mismatching is the significant error in Figure 41.



NOTES: (1) Similar configuration for DAC B.

(2) C<sub>1</sub> phase compensation (1pF to 5pF) may be required if U2 is a high-speed amplifier.

Figure 41. Bipolar Output Circuit

#### **Parallel Interface**

Data are loaded to the DAC7822 as a 12-bit parallel word. The bi-directional bus is controlled with  $\overline{CS}$  and  $R/\overline{W}$ , allowing data to be written to or read from the DAC register. To write to the device,  $\overline{CS}$  and  $R/\overline{W}$  are brought low, and data available on the data lines fills the input register. The rising edge of  $\overline{CS}$  latches the data and transfers the latched data-word to the DAC register. The DAC latches are not transparent; therefore, a write sequence must consist of a falling and rising edge on  $\overline{CS}$  in order to ensure that data are loaded to the DAC register and its analog equivalent is reflected on the DAC output.

To read data stored in the device,  $R/\overline{W}$  is held high and  $\overline{CS}$  is brought low. Data are loaded from the DAC register back to the input register and out onto the data line, where it can be read back to the controller.

#### **Cross-Reference**

The DAC7822 has an industry-standard pinout. Table 3 provides the cross-reference information.

**Table 3. Cross-Reference** 

PRODUCT	INL (LSB)	DNL (LSB)	SPECIFIED TEMPERATURE RANGE	PACKAGE DESCRIPTION	PACKAGE OPTION	CROSS- REFERENCE PART
DAC7822	±1	±1	-40°C to +125°C	40-Lead QFN	QFN-40	AD5405





21-May-2010

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
DAC7822IRTAR	ACTIVE	WQFN	RTA	40	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC7822IRTARG4	ACTIVE	WQFN	RTA	40	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC7822IRTAT	ACTIVE	WQFN	RTA	40	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
DAC7822IRTATG4	ACTIVE	WQFN	RTA	40	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

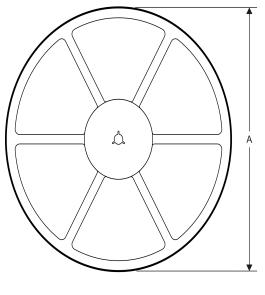
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### PACKAGE MATERIALS INFORMATION

16-Feb-2012 www.ti.com

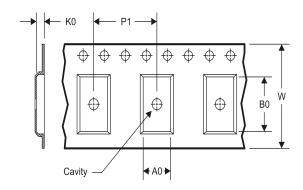
### TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**





#### **TAPE DIMENSIONS**



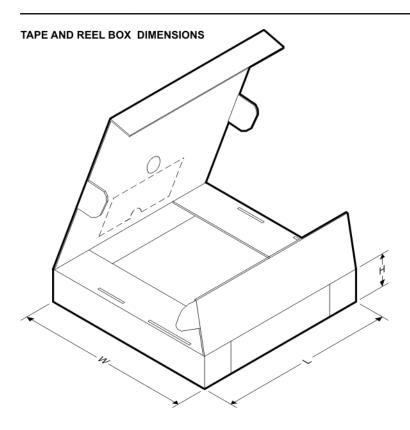
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

#### \*All dimensions are nominal

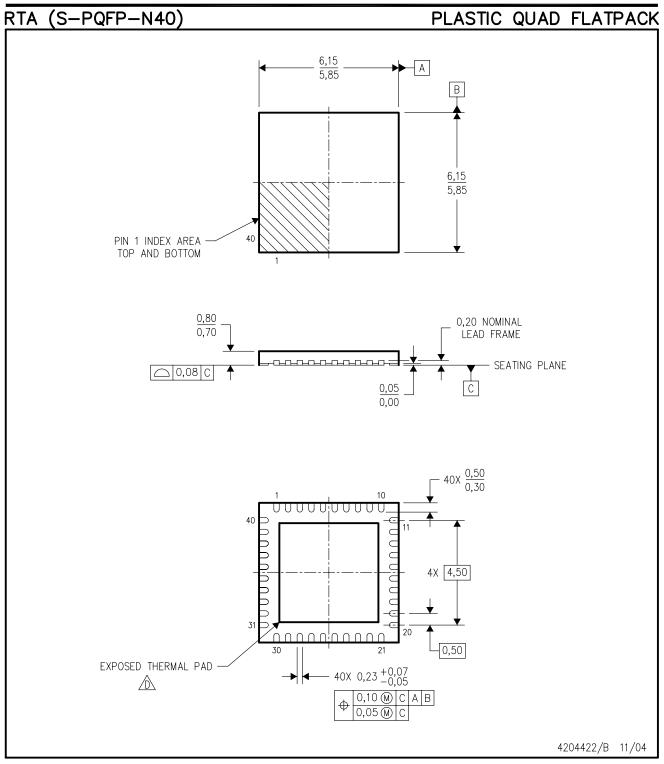
7 til dillionolollo aro nominar												
Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC7822IRTAR	WQFN	RTA	40	2000	330.0	16.4	6.3	6.3	1.5	12.0	16.0	Q2
DAC7822IRTAT	WQFN	RTA	40	250	330.0	16.4	6.3	6.3	1.5	12.0	16.0	Q2

www.ti.com 16-Feb-2012



#### \*All dimensions are nominal

Device	Package Type	Package Type Package Drawing Pins SPQ Length (mm)		Width (mm)	Height (mm)		
DAC7822IRTAR	WQFN	RTA	40	2000	336.6	336.6	28.6
DAC7822IRTAT	WQFN	RTA	40	250	336.6	336.6	28.6



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. QFN (Quad Flatpack No-Lead) Package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance.

    See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



#### THERMAL PAD MECHANICAL DATA



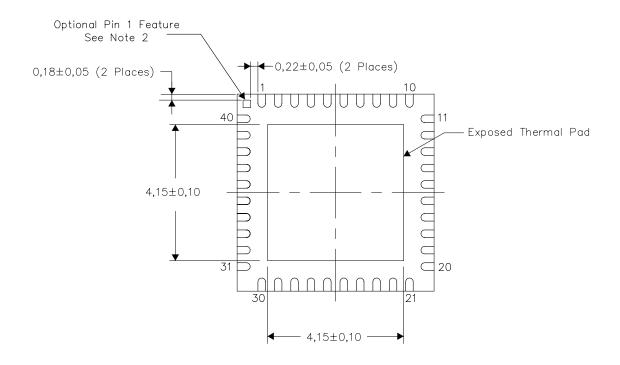
RTA (S-PWQFN-N40)

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



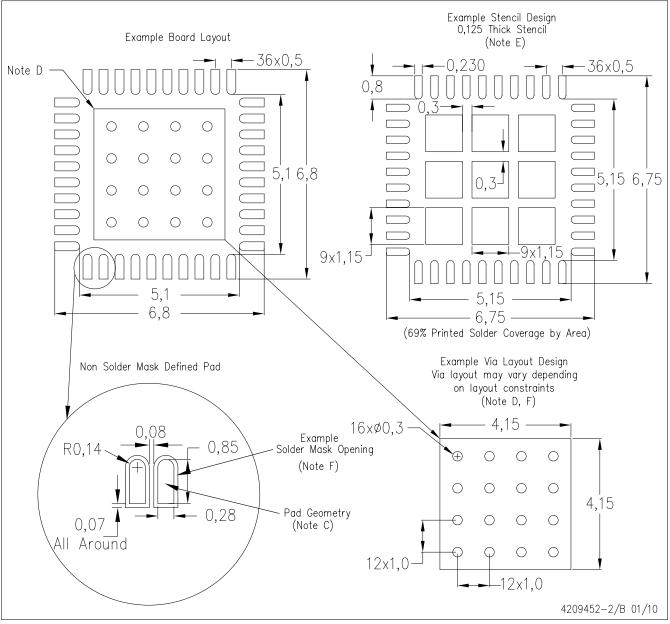
Bottom View

#### NOTES:

- 1) All linear dimensions are in millimeters
- 2) The Pin 1 Identification mark is an optional feature that may be present on some devices In addition, this Pin 1 feature if present is electrically connected to the center thermal pad and therefore should be considered when routing the board layout.

Exposed Thermal Pad Dimensions

# RTA (S-PWQFN-N40)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



#### IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

**Applications** 

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

**Products** 

Wireless Connectivity

#### Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications dataconverter.ti.com Computers and Peripherals www.ti.com/computers **Data Converters DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical Logic logic.ti.com Security www.ti.com/security Power Mgmt www.ti.com/space-avionics-defense power.ti.com Space, Avionics and Defense Microcontrollers Video and Imaging microcontroller.ti.com www.ti.com/video www.ti-rfid.com **OMAP Mobile Processors** www.ti.com/omap

TI E2E Community Home Page

www.ti.com/wirelessconnectivity

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2012, Texas Instruments Incorporated

e2e.ti.com